#### **CAVITY FUNDAMENTALS**

#### Jean Delayen

Center for Accelerator Science
Old Dominion University
and
Thomas Jefferson National Accelerator Facility





## **RF Cavity**

- Mode transformer (TEM→TM)
- Impedance transformer (Low Z→High Z)
- Space enclosed by conducting walls that can sustain an infinite number of resonant electromagnetic modes
- Shape is selected so that a particular mode can efficiently transfer its energy to a charged particle
- An isolated mode can be modeled by an LRC circuit



## **RF Cavity**

**Lorentz force** 

$$\vec{F} = q(\vec{E} + \vec{v} \times \vec{B})$$

An accelerating cavity needs to provide an electric field E longitudinal with the velocity of the particle

Magnetic fields provide deflection but no acceleration

DC electric fields can provide energies of only a few MeV

Higher energies can be obtained only by transfer of energy from traveling waves →resonant circuits

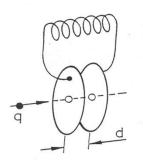
Transfer of energy from a wave to a particle is efficient only is both propagate at the same velocity





# **Equivalent Circuit for an rf Cavity**

# Simple LC circuit representing an accelerating resonator

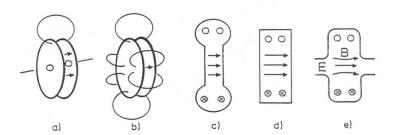


Simple lumped L-C circuit repesenting an accelerating resonator.  $\omega_0^2 = I/LC$ 

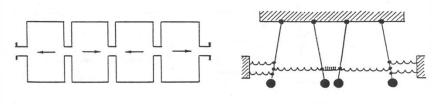
Metamorphosis of the LC circuit into an accelerating cavity

Chain of weakly coupled pillbox cavities representing an accelerating module

Chain of coupled pendula as its mechanical analogue



Metamorphosis of the L-C circuit of Fig. 1 into an accelerating cavity (after R.P.Feynman<sup>331</sup>). Fig. 5d shows the cylindrical "pillbox cavity" and Fig. 5e a slightly modified pillbox cavity with beam holes (typical  $\beta$  between 0.5 and 1.0). Fig. 5c resembles a low  $\beta$  version of the pillbox variety (0.2< $\beta$ <0.5).



Chain of weakly-coupled pillbox cavities representing an accelerating module

Chain of coupled pendula as a mechanical analogue to Fig. 6a





## **Electromagnetic Modes**

Electromagnetic modes satisfy Maxwell equations

$$\left(\nabla^2 - \frac{1}{c^2} \frac{\partial^2}{\partial t^2}\right) \left\{ \vec{E} \atop \vec{H} \right\} = 0$$

With the boundary conditions (assuming the walls are made of a material of low surface resistance)

no tangential electric field  $\vec{n} \times \vec{E} = 0$ 

no normal magnetic field  $\vec{n} \cdot \vec{H} = 0$ 



## **Electromagnetic Modes**

Assume everything  $\sim e^{-i\omega t}$   $\left( \nabla^2 + \frac{\omega^2}{c^2} \right) \left\{ \frac{\vec{E}}{\vec{H}} \right\} = 0$ 

For a given cavity geometry, Maxwell equations have an infinite number of solutions with a sinusoidal time dependence

For efficient acceleration, choose a cavity geometry and a mode where:

Electric field is along particle trajectory

Magnetic field is 0 along particle trajectory

Velocity of the electromagnetic field is matched to particle velocity



# **Accelerating Field (gradient)**

Voltage gained by a particle divided by a reference length

$$E = \frac{1}{L} \int E_z(z) \cos(\omega z / \beta c) dz$$

For velocity-of-light particles  $L = \frac{N\lambda}{2}$ 

For less-than-velocity-of-light cavities, there is no universally adopted definition of the reference length



# **Design Considerations**

$rac{H_{s, ext{max}}}{E_{acc}}$	minimum	critical field
$rac{E_{s, ext{max}}}{E_{acc}}$	<u>*</u> minimum	field emission
$\frac{\langle H_s^2 \rangle}{E_{acc}^2}$	minimum	shunt impedance, current losses
$\frac{<\!E_s^2}{E_{acc}^2}$	> minimum	dielectric losses
$rac{U}{E_{acc}^2}$	minimum maximum	control of microphonics voltage drop for high charge per bunch



## **Energy Content**

Energy density in electromagnetic field:

$$u = \frac{1}{2} \left( \varepsilon_0 \mathbf{E}^2 + \mu_0 \mathbf{H}^2 \right)$$

Because of the sinusoidal time dependence and the 90° phase shift, he energy oscillates back and forth between the electric and magnetic field

Total energy content in the cavity:

$$U = \frac{\mathcal{E}_0}{2} \int_V dV \left| \mathbf{E} \right|^2 = \frac{\mu_0}{2} \int_V dV \left| \mathbf{H} \right|^2$$



## **Power Dissipation**

Power dissipation per unit area

$$\frac{dP}{da} = \frac{\mu_0 \omega \delta}{4} \left| \mathbf{H}_{\parallel} \right|^2 = \frac{R_s}{2} \left| \mathbf{H}_{\parallel} \right|^2$$

Total power dissipation in the cavity walls

$$P = \frac{R_s}{2} \int_{\Lambda} da \left| \mathbf{H}_{\parallel} \right|^2$$



# **Quality Factor**

#### Quality Factor $Q_0$ :

$$Q_0 \equiv \frac{\text{Energy stored in cavity}}{\text{Energy dissipated in cavity walls per radian}} = \frac{\omega_0 U}{P_{diss}}$$
 
$$= \omega_0 \tau_0 = \frac{\omega_0}{\Delta \omega_0}$$

$$Q_0 = \frac{\omega \mu_0}{R_s} \frac{\int_V dV \left| \mathbf{H} \right|^2}{\int_A da \left| \mathbf{H}_{\parallel} \right|^2}$$



#### **Geometrical Factor**

Geometrical Factor QRs  $(\Omega)$ 

Product of the Quality Factor and the surface resistance Independent of size and material Depends only on shape of cavity and electromagnetic mode

$$G = QR_{s} = \omega \mu_{0} \frac{\int_{V} dV \left|\mathbf{H}\right|^{2}}{\int_{A} da \left|\mathbf{H}_{\parallel}\right|^{2}} = 2\pi \sqrt{\frac{\mu_{0}}{\varepsilon_{0}}} \frac{1}{\lambda} \frac{\int_{V} dV \left|\mathbf{H}\right|^{2}}{\int_{A} da \left|\mathbf{H}_{\parallel}\right|^{2}} = \frac{2\pi \eta}{\lambda} \frac{\int_{V} dV \left|\mathbf{H}\right|^{2}}{\int_{A} da \left|\mathbf{H}_{\parallel}\right|^{2}}$$

 $\eta \approx 377\Omega$  Impedance of vacuum



# Shunt Impedance, R/Q

Shunt impedance R<sub>sh</sub>:

$$R_{sh} \equiv \frac{V_c^2}{P_{diss}} \quad \text{in } \Omega$$

 $V_c$  = accelerating voltage

Note: Sometimes the shunt impedance is defined as or quoted as impedance per unit length (ohm/m)  $\frac{1}{2}$ 

 $\frac{V_c^2}{2P_{diss}}$ 

R/Q (in  $\Omega$ )

$$\frac{R}{Q} = \frac{V^2}{P} \frac{P}{\omega U} = \frac{E^2}{U} \frac{L^2}{\omega}$$



# Q – Geometrical Factor (Q R<sub>s</sub>)

Q: Energy content Energy disspated during one radian = 
$$\omega \frac{U}{P} = \omega \tau = \frac{\omega}{\Delta \omega}$$

Rough estimate (factor of 2) for fundamental mode

$$\omega = \frac{2\pi c}{\lambda} \simeq \frac{2\pi}{\sqrt{\varepsilon_0 \mu_0}} \frac{1}{2L} \qquad U = \frac{\mu_0}{2} \int H^2 dv \simeq \frac{\mu_0}{2} \frac{1}{2} H_0^2 \frac{\pi L^3}{6}$$

$$P = \frac{1}{2} R_s \int H^2 dA = \frac{1}{2} R_s \frac{1}{2} H_0^2 \pi L^2$$

$$QR_s \sim \frac{\pi}{6} \sqrt{\frac{\mu_0}{\varepsilon_0}} = 200\Omega$$

 $G=QR_s$  is size (frequency) and material independent. It depends only on the mode geometry It is independent of number of cells For superconducting elliptical cavities  $QR_s\sim 275\Omega$ 



# Shunt Impedance (R<sub>sh</sub>), R<sub>sh</sub> R<sub>s</sub>, R/Q

$$R_{sh} = \frac{V^2}{P} \simeq \frac{E_z^2 L^2}{\frac{1}{2} R_s H_0^2 \pi L^2 \frac{1}{2}}$$

In practice for elliptical cavities

$$R_{sh}R_s \simeq 33,000 \left(\Omega^2\right)$$
 per cell  $R_{sh}/Q \simeq 100\Omega$  per cell

 $R_{sh} R_s$  and  $R_{sh} / Q$ 

Independent of size (frequency) and material

Depends on mode geometry

Proportional to number of cells





# Power Dissipated per Unit Length or Unit Area

$$\frac{P}{L} \propto \frac{1}{\frac{R}{Q}} \frac{E^2 R_S}{\omega}$$

For normal conductors  $R_{\rm s} \propto \omega^{1/2}$ 

$$R_{\rm S} \propto \omega^{1/2}$$

$$rac{P}{L} \propto \omega^{-rac{1}{2}}$$
  $rac{P}{A} \propto \omega^{rac{1}{2}}$ 

For superconductors  $R_{\rm s} \propto \omega^2$ 

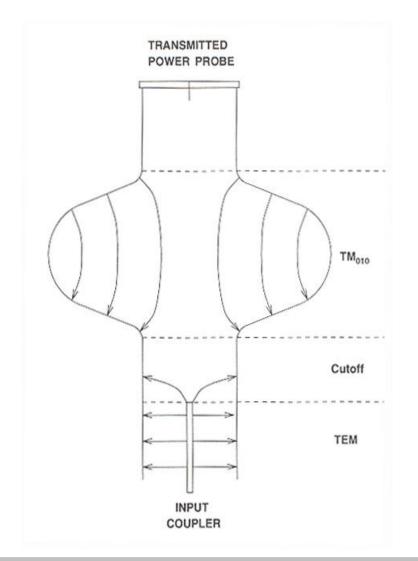
$$R_{\rm s} \propto \omega^2$$

$$\frac{P}{L} \propto \omega$$
 $\frac{P}{A} \propto \omega^2$ 



# **External Coupling**

- Consider a cavity connected to an rf source
- A coaxial cable carries power from an rf source to the cavity
- The strength of the input coupler is adjusted by changing the penetration of the center conductor
- There is a fixed output coupler, the transmitted power probe, which picks up power transmitted through the cavity. This is usually very weakly coupled







# **Cavity with External Coupling**

Consider the rf cavity after the rf is turned off. Stored energy U satisfies the equation:  $\frac{dU}{dt} = -P_{tot}$ 

Total power being lost,  $P_{tot}$  is:  $P_{tot} = P_{diss} + P_{e} + P_{t}$ 

 $P_e$  is the power leaking back out the input coupler.  $P_t$  is the power coming out the transmitted power coupler.

Typically  $P_t$  is very small  $\Rightarrow P_{tot} \approx P_{diss} + P_e$ 

Recall 
$$Q_0 \equiv \frac{\omega_0 U}{P_{disc}}$$

Similarly define a "loaded" quality factor  $Q_L$ :  $Q_L \equiv \frac{\omega_0 U}{P_{tot}}$ 

Now 
$$\frac{dU}{dt} = -\frac{\omega_0 U}{Q_L} \implies U = U_0 e^{-\frac{\omega_0 t}{Q_L}}$$

 $\therefore$  energy in the cavity decays exponentially with time constant:  $\tau_L = \frac{Q_L}{\omega_0}$ 



# **Cavity with External Coupling**

Equation 
$$\frac{P_{tot}}{\omega_0 U} = \frac{P_{diss} + P_e}{\omega_0 U}$$

suggests that we can assign a quality factor to each loss mechanism, such that

$$\frac{1}{Q_L} = \frac{1}{Q_0} + \frac{1}{Q_e}$$

where, by definition, 
$$Q_e \equiv \frac{\omega_0 U}{P_e}$$

Typical values for CEBAF 7-cell cavities: Q<sub>0</sub>=1x10<sup>10</sup>, Q<sub>e</sub> ≈Q<sub>L</sub>=2x10<sup>7</sup>.



# **Cavity with External Coupling**

• Define "coupling parameter":  $\beta \equiv \frac{Q_0}{Q_o}$ 

therefore 
$$\frac{1}{Q_L} = \frac{(1+\beta)}{Q_0}$$

$$\beta$$
 is equal to:  $\beta = \frac{P_e}{P_{diss}}$ 

It tells us how strongly the couplers interact with the cavity.
 Large β implies that the power leaking out of the coupler is large compared to the power dissipated in the cavity walls.





# **Several Loss Mechanisms**

$$P = \sum P_i$$

 $P = \sum_{i} P_{i}$  -wall losses

- -power absorbed by beam
- -coupling to outside world

Associate Q will each loss mechanism

$$Q_i = \omega \frac{U}{P_i}$$

(index 0 is reserved for wall losses)

Loaded Q: Q

$$\frac{1}{Q_L} = \frac{\sum P_i}{\omega U} = \sum \frac{1}{Q_i}$$

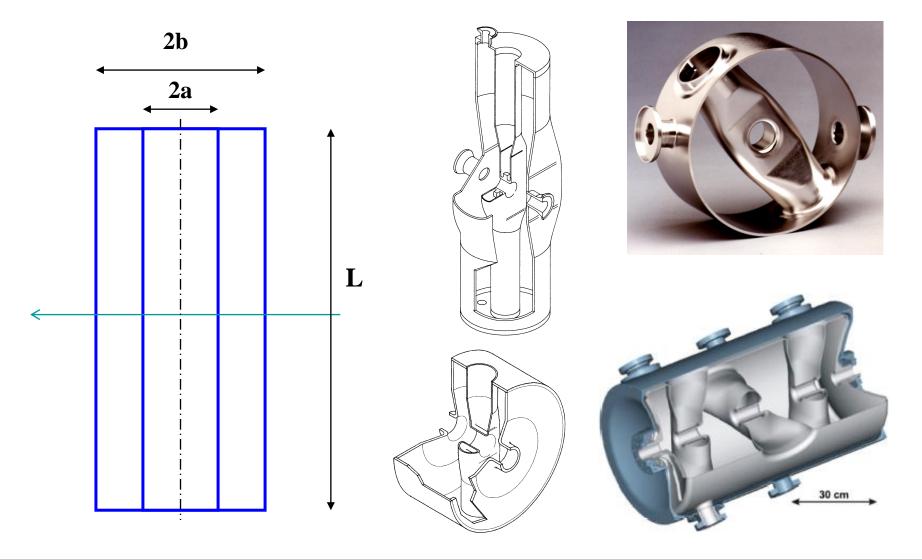
Coupling coefficient:

$$\beta_i = \frac{Q_0}{Q_i} = \frac{P_i}{P_0}$$

$$Q_L = \frac{Q_0}{1 + \sum \beta_i}$$



# **Another Simple Model: Coaxial Half-wave Resonator**





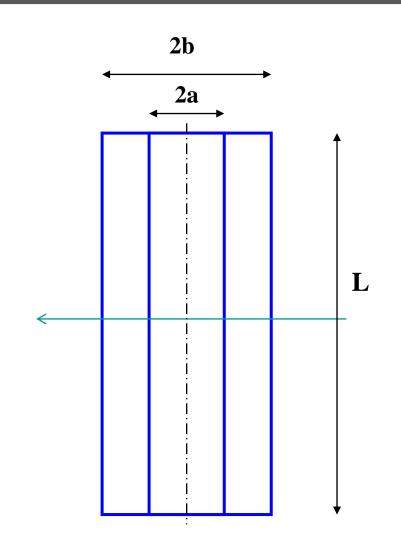


#### Capacitance per unit length

$$C = \frac{2\pi\varepsilon_0}{\ln\left(\frac{b}{a}\right)} = \frac{2\pi\varepsilon_0}{\ln\left(\frac{1}{\rho_0}\right)}$$

Inductance per unit length

$$L = \frac{\mu_0}{2\pi} \ln\left(\frac{b}{r_0}\right) = \frac{\mu_0}{2\pi} \ln\left(\frac{1}{\rho_0}\right)$$





#### Center conductor voltage

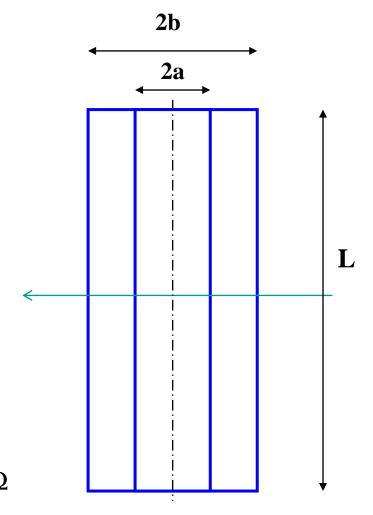
$$V(z) = V_0 \cos\left(\frac{2\pi}{\lambda}z\right)$$

#### Center conductor current

$$I(z) = I_0 \sin\left(\frac{2\pi}{\lambda}z\right)$$

#### Line impedance

$$Z_0 = \frac{V_0}{I_0} = \frac{\eta}{2\pi} \ln\left(\frac{1}{\rho_0}\right), \qquad \eta = \sqrt{\frac{\mu_0}{\varepsilon_0}} \simeq 377\Omega$$





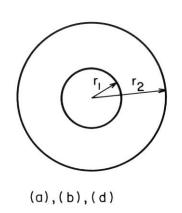
#### **Peak Electric Field**

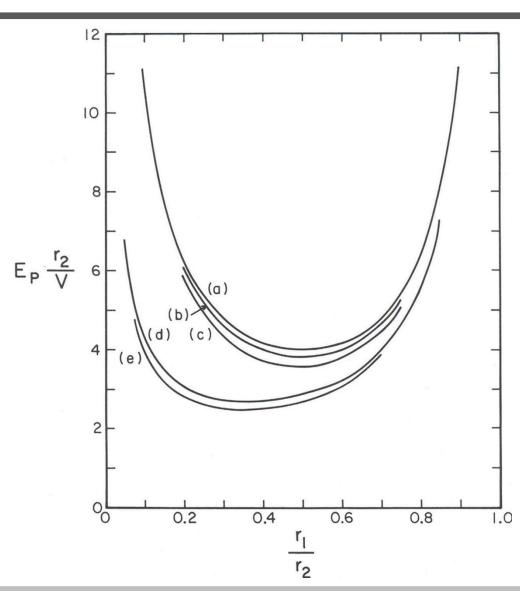
d: coaxial cylinders

 $V_p$ : Voltage on center conductor

Outer conductor at ground

E<sub>p</sub>: Peak field on center conductor







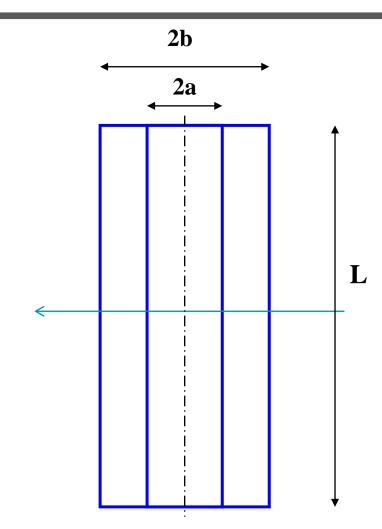


#### Peak magnetic field

$$\frac{V_p}{b} = \begin{cases} \eta & H \\ c & B \\ 300 & B \end{cases} \rho_0 \ln\left(\frac{1}{\rho_0}\right) \qquad \begin{cases} \text{m, A/m} \\ \text{m, T} \\ \text{cm, G} \end{cases}$$

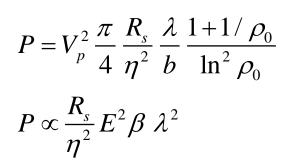
 $V_p$ : Voltage across loading capacitance

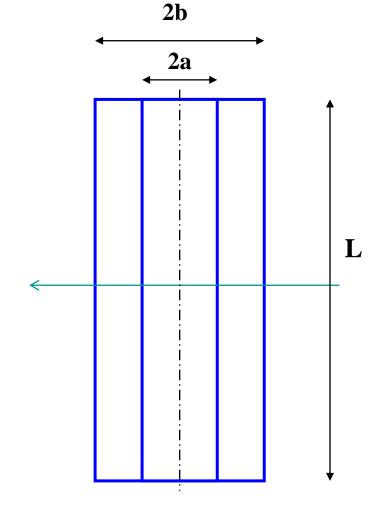
 $B \simeq 9$  mT at 1 MV/m





Power dissipation (ignore losses in the shorting plate)

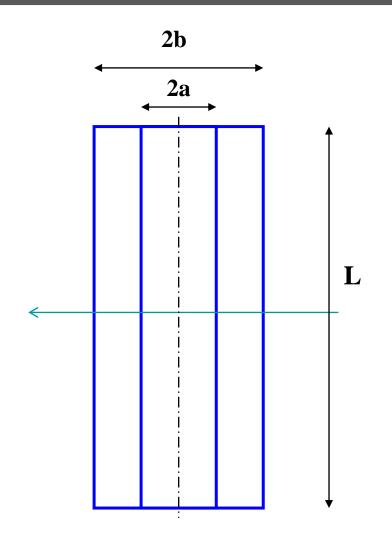






#### **Energy content**

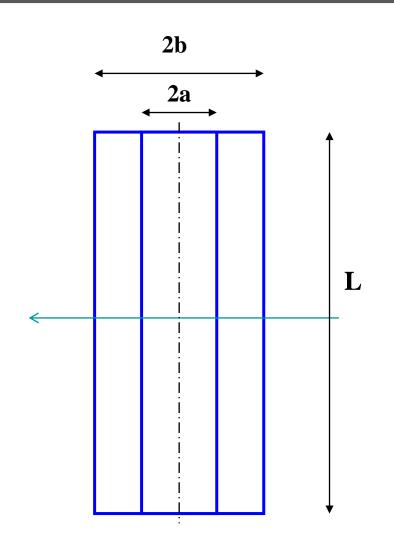
$$U = V_p^2 \frac{\pi \varepsilon_0}{4} \lambda \frac{1}{\ln(1/\rho_0)}$$
$$U \propto \varepsilon_0 E^2 \beta^2 \lambda^3$$





#### Geometrical factor

$$G = QR_s = 2\pi \eta \frac{b}{\lambda} \frac{\ln(1/\rho_0)}{1+1/\rho_0}$$
$$G \propto \eta \beta$$

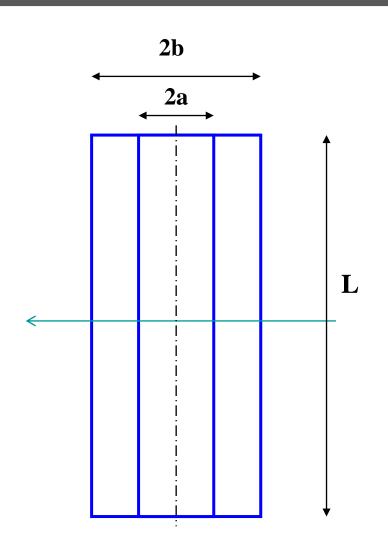




Shunt impedance  $\left(4V_p^2/P\right)$ 

$$R_{sh} = \frac{\eta^2}{R_s} \frac{16}{\pi} \frac{b}{\lambda} \frac{\ln^2 \rho_0}{1 + 1/\rho_0}$$

$$R_{sh} R_s \propto \eta^2 \beta$$

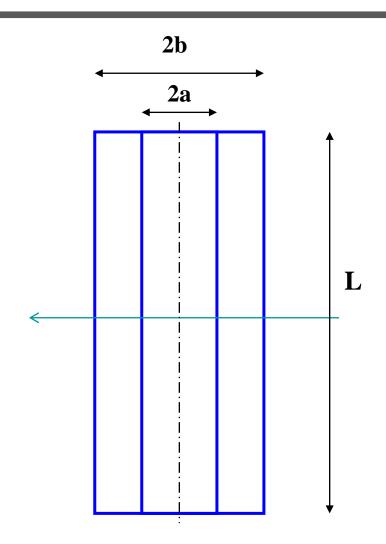




R/Q

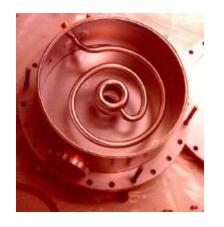
$$\frac{R_{sh}}{Q} = \frac{8}{\pi^2} \eta \ln(1/\rho_0)$$

$$\frac{R_{sh}}{Q} \propto \eta$$





# Some Real Geometries ( $\lambda/4$ )

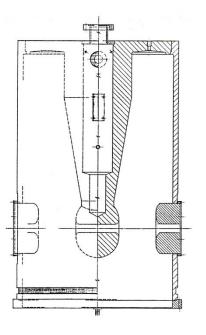








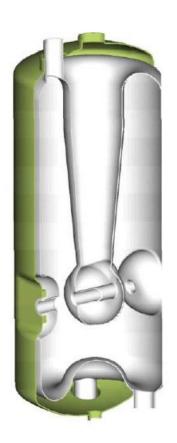






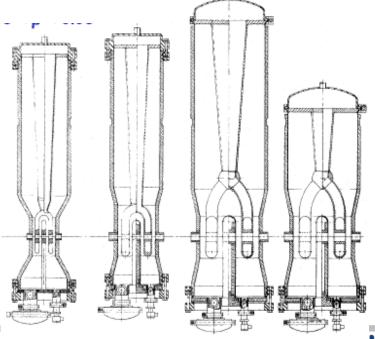


# Some Real Geometries ( $\lambda/4$ )





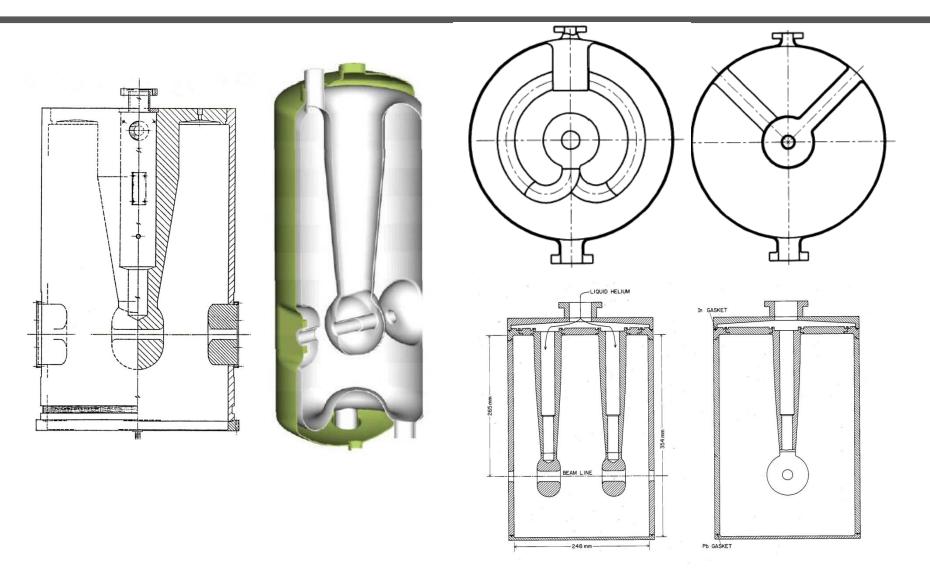








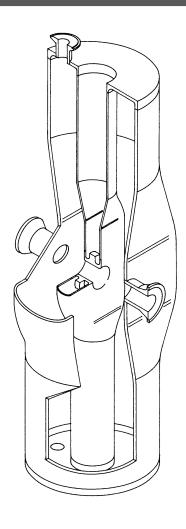
#### **λ/4 Resonant Lines**



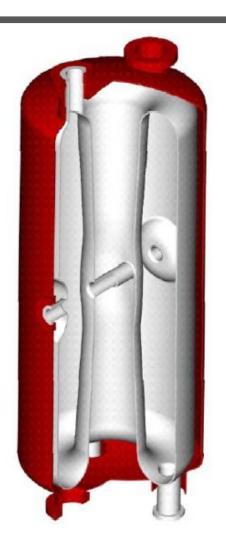




### λ/2 Resonant Lines



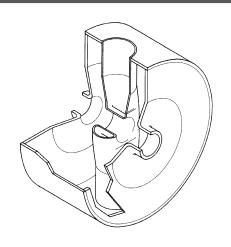






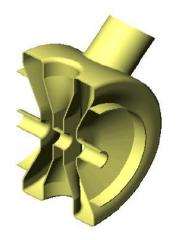


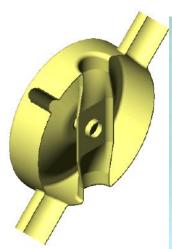
# λ/2 Resonant Lines – Single-Spoke

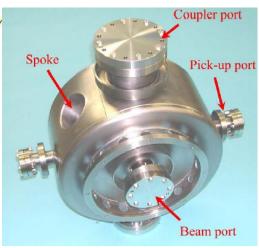








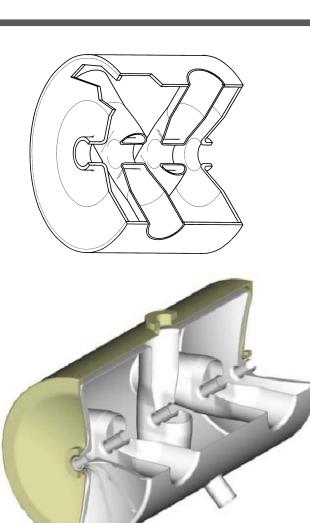








### λ/2 Resonant Lines – Double and Triple-Spoke

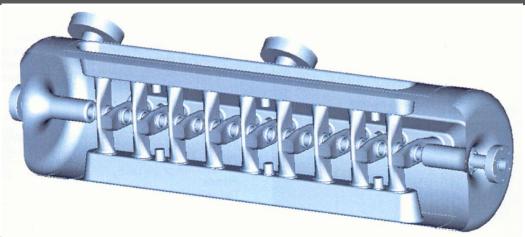


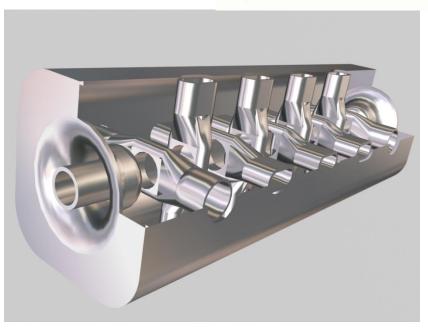






# **λ/2 Resonant Lines – Multi-Spoke**











# 1300 MHz 9-cell







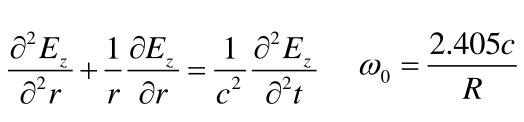
### Pill Box Cavity

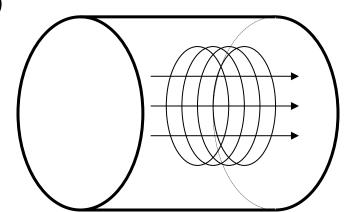
### Hollow right cylindrical enclosure

Operated in the  $TM_{010}$  mode  $H_z = 0$ 

$$H_z = 0$$

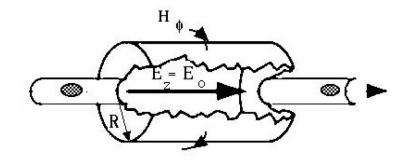
TM<sub>010</sub> mode





$$E_z(r, z, t) = E_0 J_0 \left( 2.405 \frac{r}{R} \right) e^{-i\omega_0 t}$$

$$H_{\varphi}(r,z,t) = -i\frac{E_0}{\mu_0 c} J_1 \left(2.405 \frac{r}{R}\right) e^{-i\omega_0 t}$$





## **Modes in Pill Box Cavity**

- TM<sub>010</sub>
  - Electric field is purely longitudinal
  - Electric and magnetic fields have no angular dependence
  - Frequency depends only on radius, independent on length
- **TM**<sub>0mn</sub>
  - Monopoles modes that can couple to the beam and exchange energy
- TM<sub>1mn</sub>
  - Dipole modes that can deflect the beam
- TE modes
  - No longitudinal E field
  - Cannot couple to the beam





# **TM Modes in a Pill Box Cavity**

$$\frac{E_r}{E_0} = -\frac{n\pi}{x_{lm}} \frac{R}{L} J_l' \left( x_{lm} \frac{r}{R} \right) \sin \left( n\pi \frac{z}{L} \right) \cos l\varphi$$

$$\frac{E_{\varphi}}{E_0} = \frac{ln\pi}{x_{lm}^2} \frac{R^2}{rL} J_l \left( x_{lm} \frac{r}{R} \right) \sin \left( n\pi \frac{z}{L} \right) \sin l\varphi$$

$$\frac{E_z}{E_0} = J_l \left( x_{lm} \frac{r}{R} \right) \sin \left( n\pi \frac{z}{L} \right) \cos l\varphi$$

$$\frac{H_r}{E_0} = -i\omega\varepsilon \frac{l}{x_{lm}^2} \frac{R^2}{r} J_l \left( x_{lm} \frac{r}{R} \right) \cos\left( n\pi \frac{z}{L} \right) \sin l\varphi$$

$$\frac{H_{\varphi}}{E_0} = -i\omega\varepsilon \frac{R}{x_{lm}} J_l' \left( x_{lm} \frac{r}{R} \right) \cos\left( n\pi \frac{z}{L} \right) \cos l\varphi$$

$$\frac{H_z}{E_0} = 0$$

$$\omega_{lmn} = c\sqrt{\left(\frac{x_{lm}}{R}\right)^2 + \left(\frac{\pi n}{L}\right)^2}$$

 $x_{lm}$  is the mth root of  $J_l(x)$ 



# TM<sub>010</sub> Mode in a Pill Box Cavity

$$E_r = E_{\varphi} = 0$$

$$E_z = E_0 J_0 \left( x_{01} \frac{r}{R} \right)$$

$$H_r = H_z = 0$$

$$H_{\varphi} = -i\omega\varepsilon E_0 \frac{R}{x_{01}} J_1 \left( x_{01} \frac{r}{R} \right)$$

$$\omega = x_{01} \frac{c}{R}$$

$$x_{01} = 2.405$$

$$R = \frac{x_{01}}{2\pi}\lambda = 0.383\lambda$$



# TM<sub>010</sub> Mode in a Pill Box Cavity

### **Energy content**

$$U = \varepsilon_0 E_0^2 \frac{\pi}{2} J_1^2(x_{01}) LR^2$$

### **Power dissipation**

$$P = E_0^2 \frac{R_s}{\eta^2} \pi J_1^2(x_{01})(R+L)R$$

$$x_{01} = 2.40483$$

$$J_1(x_{01}) = 0.51915$$

#### **Geometrical factor**

$$G = \eta \frac{x_{01}}{2} \frac{L}{(R+L)}$$



### TM010 Mode in a Pill Box Cavity

#### **Energy Gain**

$$\Delta W = E_0 \frac{\lambda}{\pi} \sin \frac{\pi L}{\lambda}$$

#### **Gradient**

$$E_{acc} = \frac{\Delta W}{\lambda / 2} = E_0 \frac{2}{\pi} \sin \frac{\pi L}{\lambda}$$

#### **Shunt impedance**

$$R_{sh} = \frac{\eta^2}{R_s} \frac{1}{\pi^3 J_1^2(x_{01})} \frac{\lambda^2}{R(R+L)} \sin^2\left(\frac{\pi L}{\lambda}\right)$$



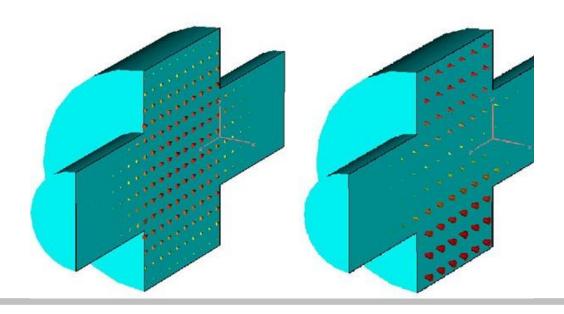
### **Real Cavities**

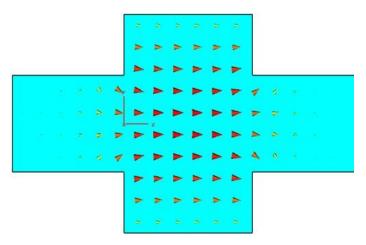
#### Beam tubes reduce the electric field on axis

**Gradient decreases** 

**Peak fields increase** 

R/Q decreases

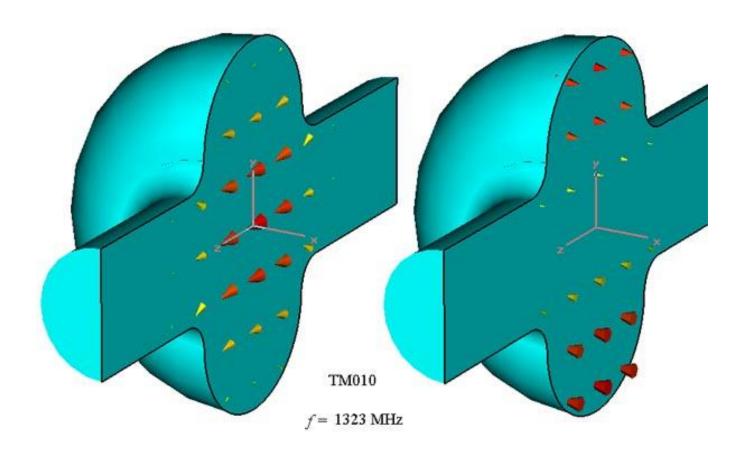








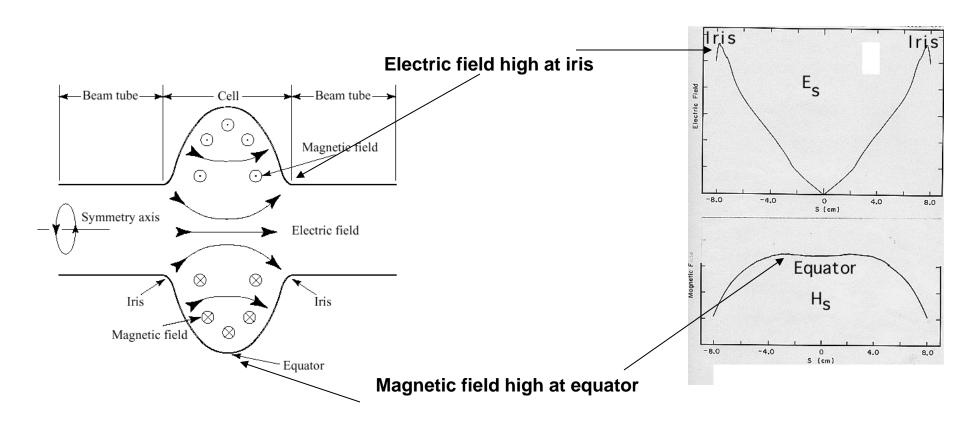
### **Real Cavities**







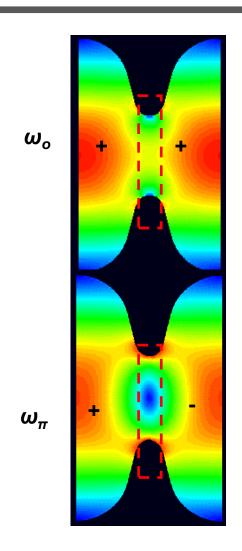
## **Single Cell Cavities**

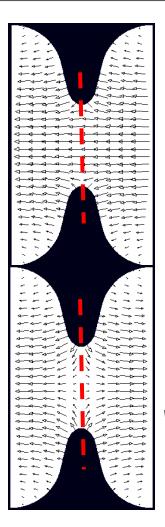






### Coupling between cells





Symmetry plane for the H field

The normalized difference between these frequencies is a measure of the energy flow via the coupling region

Symmetry plane for the E field which is an additional solution

$$k_{cc} = \frac{\omega_{\pi} - \omega_0}{\frac{\omega_{\pi} + \omega_0}{2}}$$





### **Multi-Cell Cavities**

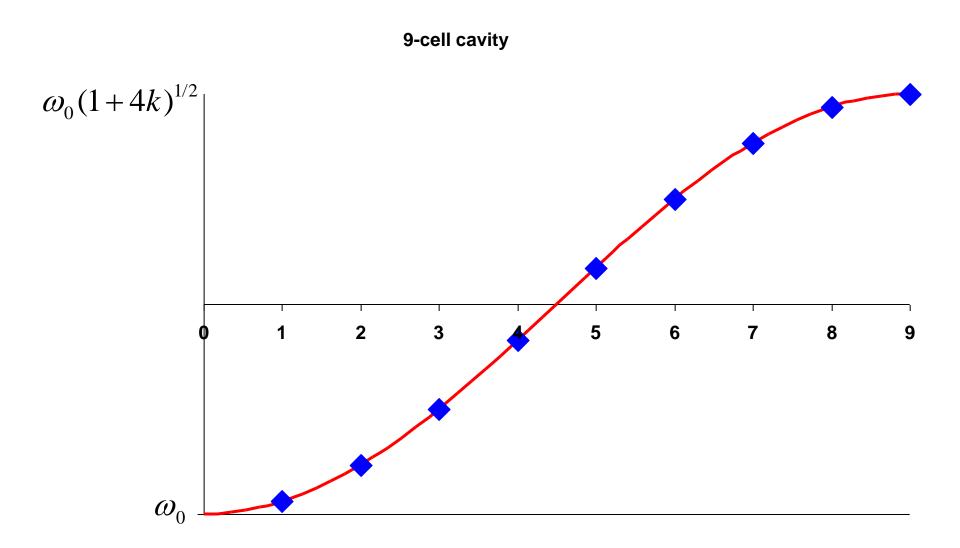
Mode frequencies: 
$$\frac{\omega_m^2}{\omega_0^2} = 1 + 2k \left( 1 - \cos \frac{\pi m}{n} \right)$$

$$\frac{\omega_n - \omega_{n-1}}{\omega_0} \simeq k \left( 1 - \cos \frac{\pi}{n} \right) \simeq \frac{k}{2} \left( \frac{\pi}{n} \right)^2$$

Voltages in cells: 
$$V_j^m = \sin\left(\pi m \frac{2j-1}{2n}\right)$$



# **Pass-Band Modes Frequencies**





### **Cell Excitations in Pass-Band Modes**





